

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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## SWITCHING

### N-CHANNEL POWER MOS FET

#### DESCRIPTION

The 2SK3716 is N-channel MOS Field Effect Transistor designed for high current switching applications.

#### FEATURES

- Super low on-state resistance:  
 $R_{DS(on)1} = 6.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 30 \text{ A)}$   
 $R_{DS(on)2} = 9.1 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 30 \text{ A)}$
- Low  $C_{iss}$ :  $C_{iss} = 2700 \text{ pF TYP.}$
- Built-in gate protection diode

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

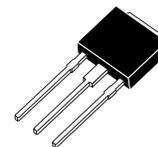
|  |                |             |                  |
|--|----------------|-------------|------------------|
| Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )   | $V_{DSS}$      | 40          | V                |
| Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )    | $V_{GSS}$      | $\pm 20$    | V                |
| Drain Current (DC) ( $T_c = 25^\circ\text{C}$ )      | $I_{D(DC)}$    | $\pm 60$    | A                |
| Drain Current (pulse) <sup>Note1</sup>               | $I_{D(pulse)}$ | $\pm 240$   | A                |
| Total Power Dissipation ( $T_c = 25^\circ\text{C}$ ) | $P_{T1}$       | 84          | W                |
| Total Power Dissipation ( $T_A = 25^\circ\text{C}$ ) | $P_{T2}$       | 1.0         | W                |
| Channel Temperature                                  | $T_{ch}$       | 150         | $^\circ\text{C}$ |
| Storage Temperature                                  | $T_{stg}$      | -55 to +150 | $^\circ\text{C}$ |
| Repetitive Avalanche Current <sup>Note2</sup>        | $I_{AS}$       | 32          | A                |
| Repetitive Avalanche Energy <sup>Note2</sup>         | $E_{AS}$       | 100         | mJ               |

- Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$   
**2.**  $V_{DD} = 20 \text{ V}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$ ,  $T_{ch(peak)} \leq 150^\circ\text{C}$

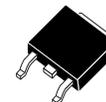
#### ORDERING INFORMATION

| PART NUMBER | PACKAGE        |
|-------------|----------------|
| 2SK3716     | TO-251 (MP-3)  |
| 2SK3716-Z   | TO-252 (MP-3Z) |

(TO-251)



(TO-252)



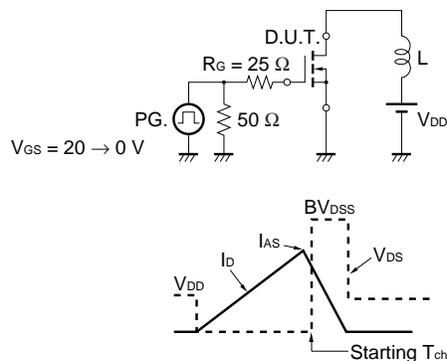
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**ELECTRICAL CHARACTERISTICS (TA = 25°C)**

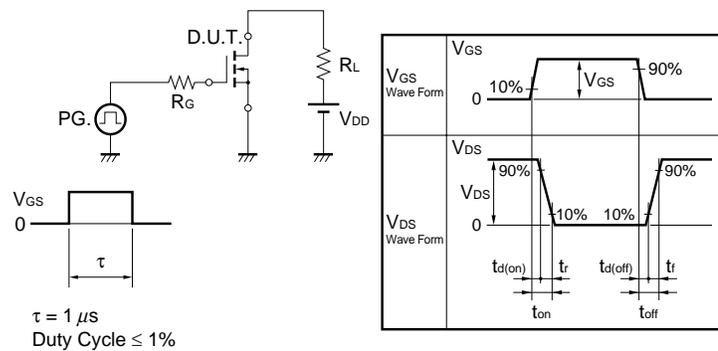
| CHARACTERISTICS                                     | SYMBOL        | TEST CONDITIONS                                 | MIN. | TYP. | MAX.     | UNIT             |
|---|---------------|---|------|------|----------|------------------|
| Zero Gate Voltage Drain Current                     | $I_{DSS}$     | $V_{DS} = 40\text{ V}, V_{GS} = 0\text{ V}$     |      |      | 10       | $\mu\text{A}$    |
| Gate Leakage Current                                | $I_{GSS}$     | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ |      |      | $\pm 10$ | $\mu\text{A}$    |
| Gate Cut-off Voltage                                | $V_{GS(off)}$ | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$       | 1.5  | 2.0  | 2.5      | V                |
| Forward Transfer Admittance <sup>Note</sup>         | $ y_{fs} $    | $V_{DS} = 10\text{ V}, I_D = 30\text{ A}$       | 22   | 43   |          | S                |
| Drain to Source On-state Resistance <sup>Note</sup> | $R_{DS(on)1}$ | $V_{GS} = 10\text{ V}, I_D = 30\text{ A}$       |      | 5.2  | 6.5      | $\text{m}\Omega$ |
|   | $R_{DS(on)2}$ | $V_{GS} = 4.5\text{ V}, I_D = 30\text{ A}$      |      | 6.6  | 9.1      | $\text{m}\Omega$ |
| Input Capacitance                                   | $C_{iss}$     | $V_{DS} = 10\text{ V}$                          |      | 2700 |          | pF               |
| Output Capacitance                                  | $C_{oss}$     | $V_{GS} = 0\text{ V}$                           |      | 770  |          | pF               |
| Reverse Transfer Capacitance                        | $C_{rss}$     | $f = 1\text{ MHz}$                              |      | 290  |          | pF               |
| Turn-on Delay Time                                  | $t_{d(on)}$   | $V_{DD} = 20\text{ V}, I_D = 30\text{ A}$       |      | 11   |          | ns               |
| Rise Time   | $t_r$         | $V_{GS} = 10\text{ V}$                          |      | 13   |          | ns               |
| Turn-off Delay Time                                 | $t_{d(off)}$  | $R_G = 0\ \Omega$                               |      | 69   |          | ns               |
| Fall Time   | $t_f$         |   |      | 14   |          | ns               |
| Total Gate Charge                                   | $Q_G$         | $V_{DD} = 32\text{ V}$                          |      | 50   |          | nC               |
| Gate to Source Charge                               | $Q_{GS}$      | $V_{GS} = 10\text{ V}$                          |      | 9    |          | nC               |
| Gate to Drain Charge                                | $Q_{GD}$      | $I_D = 60\text{ A}$                             |      | 13   |          | nC               |
| Body Diode Forward Voltage <sup>Note</sup>          | $V_{F(S-D)}$  | $I_F = 60\text{ A}, V_{GS} = 0\text{ V}$        |      | 0.94 | 1.5      | V                |
| Reverse Recovery Time                               | $t_{rr}$      | $I_F = 60\text{ A}, V_{GS} = 0\text{ V}$        |      | 40   |          | ns               |
| Reverse Recovery Charge                             | $Q_{rr}$      | $di/dt = 100\text{ A}/\mu\text{s}$              |      | 42   |          | nC               |

**Note** Pulsed

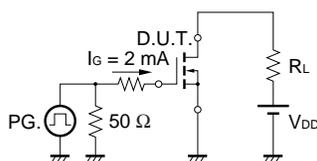
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



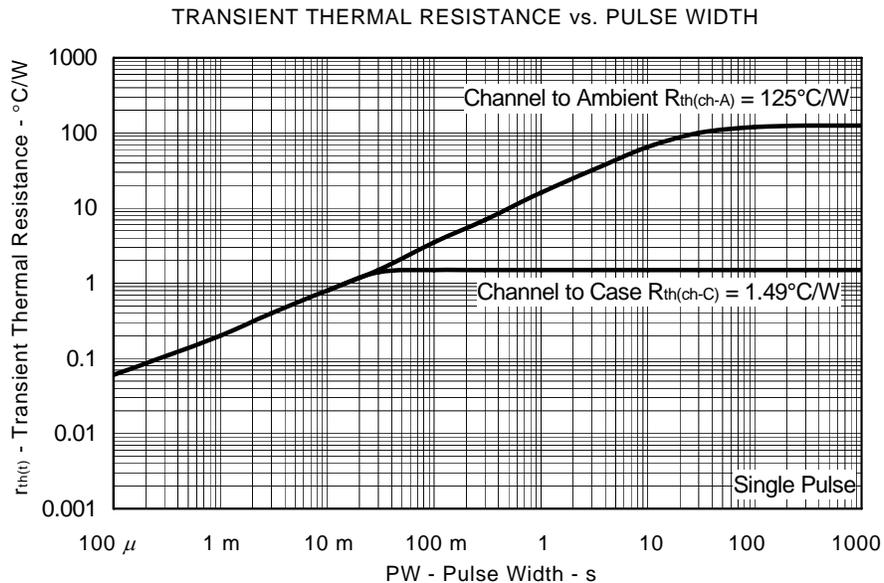
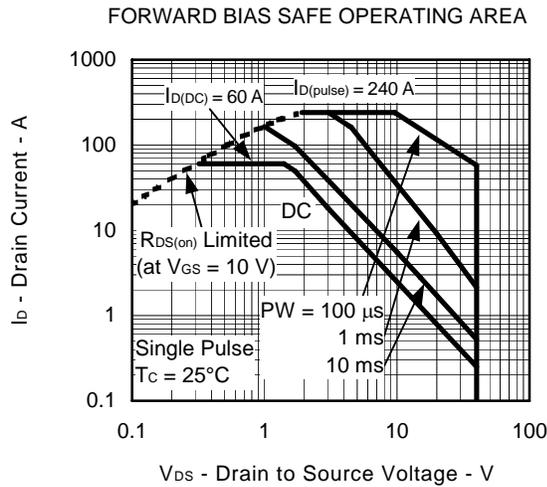
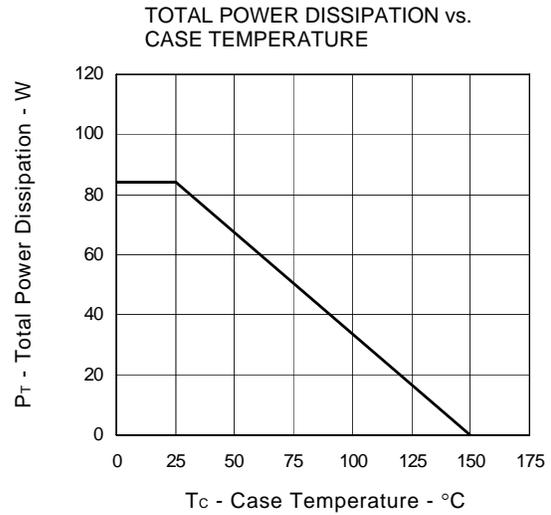
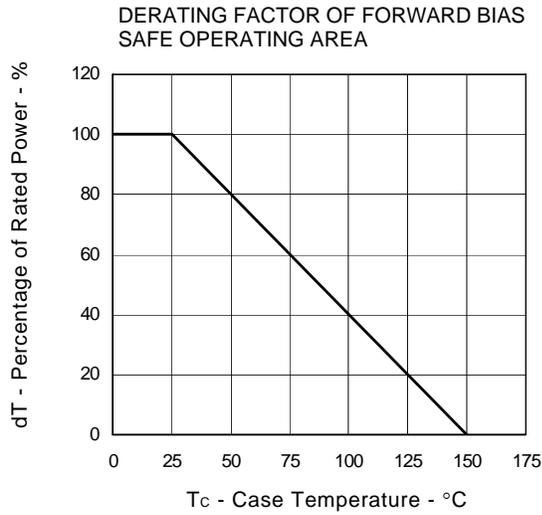
**TEST CIRCUIT 2 SWITCHING TIME**



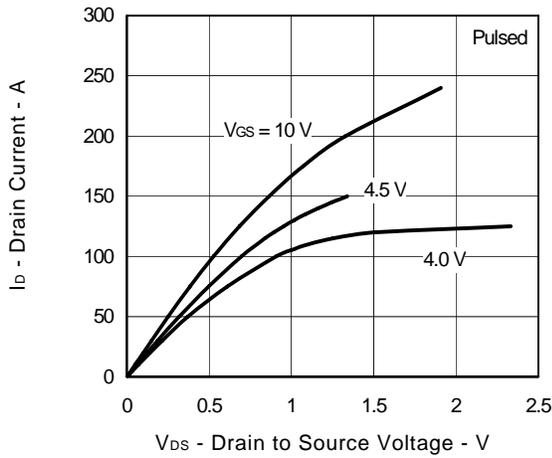
**TEST CIRCUIT 3 GATE CHARGE**



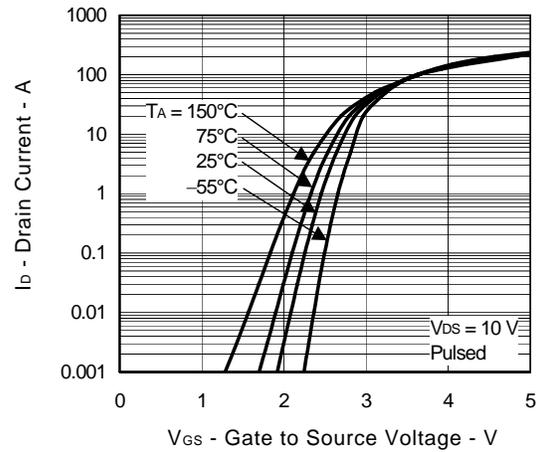
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



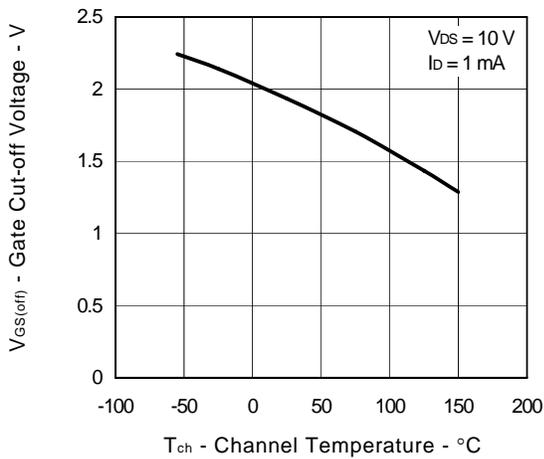
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



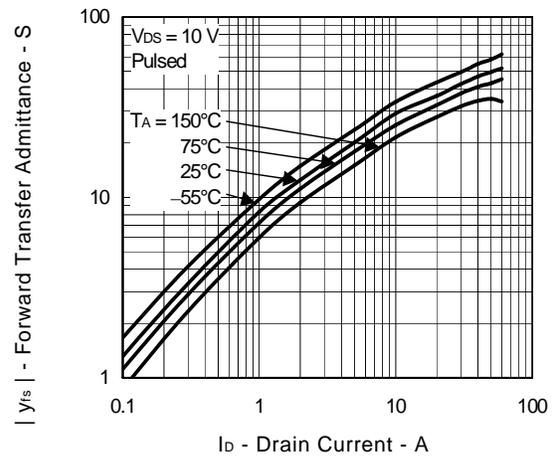
FORWARD TRANSFER CHARACTERISTICS



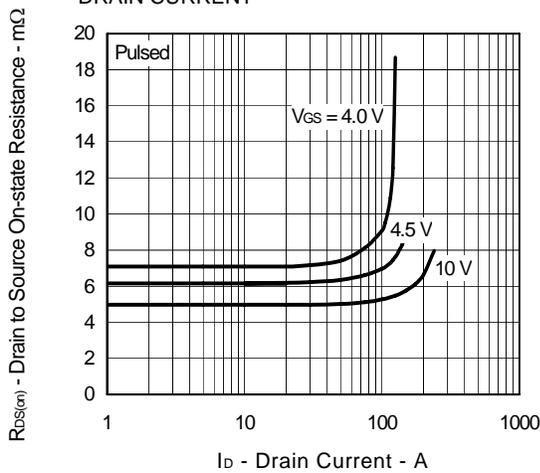
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



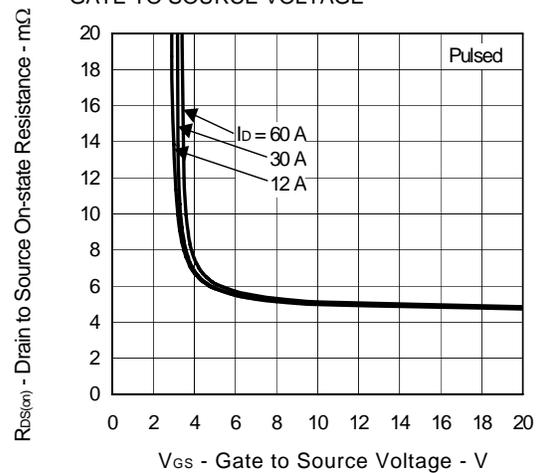
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



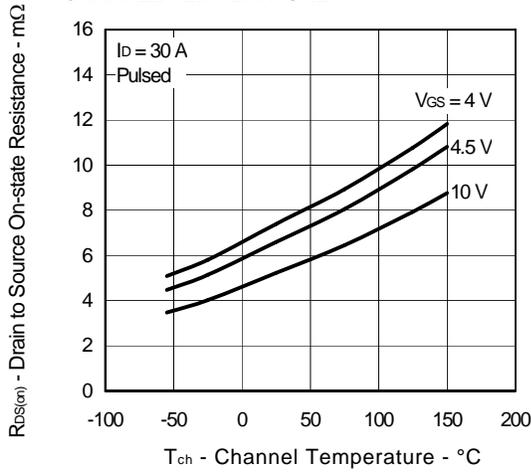
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



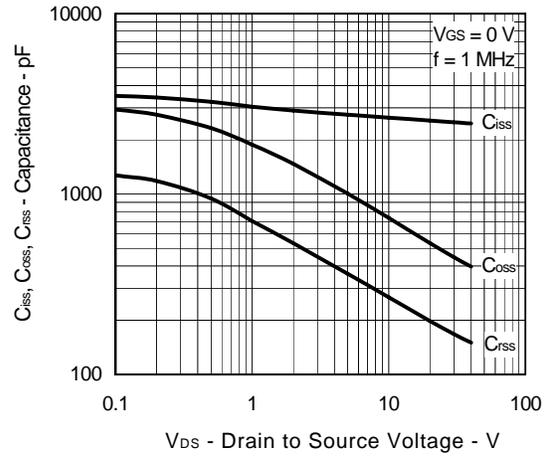
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



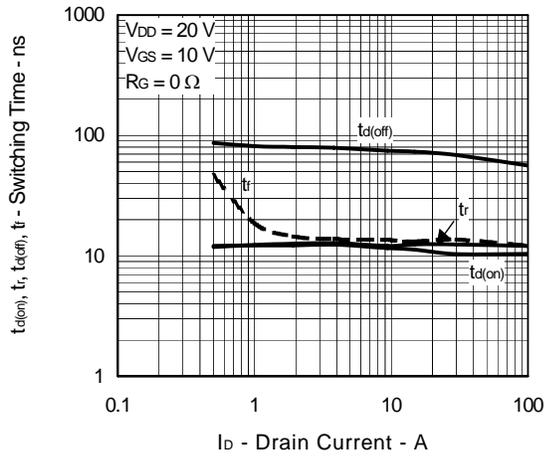
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



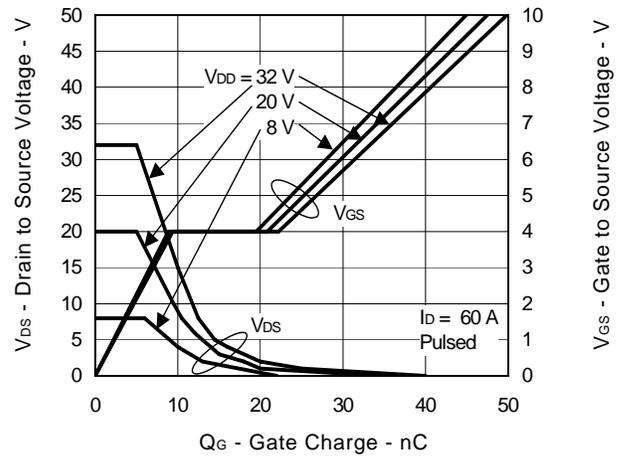
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



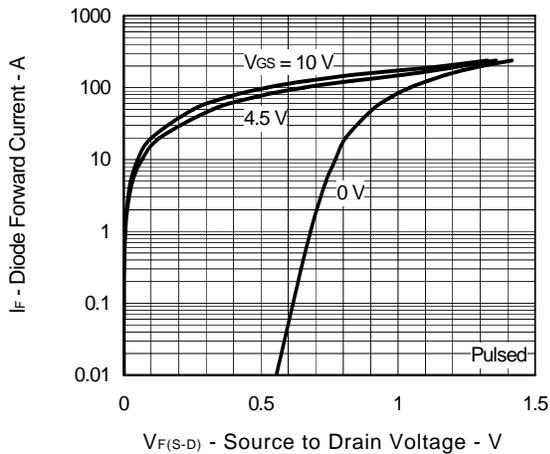
SWITCHING CHARACTERISTICS



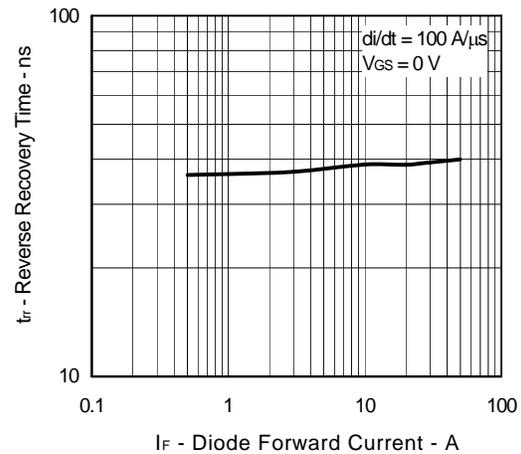
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

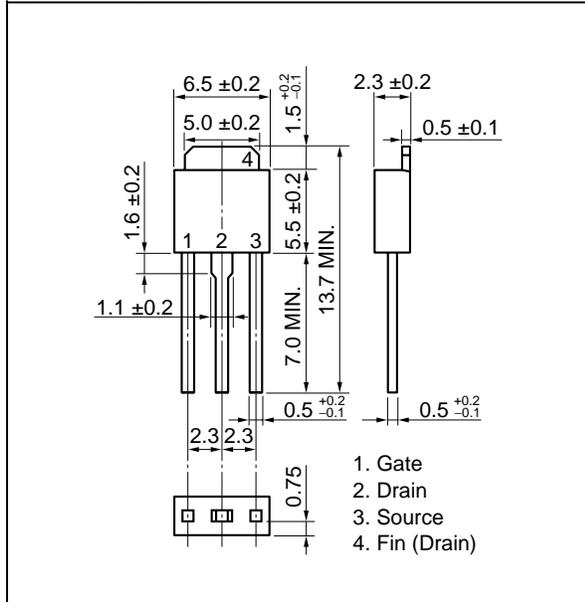


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

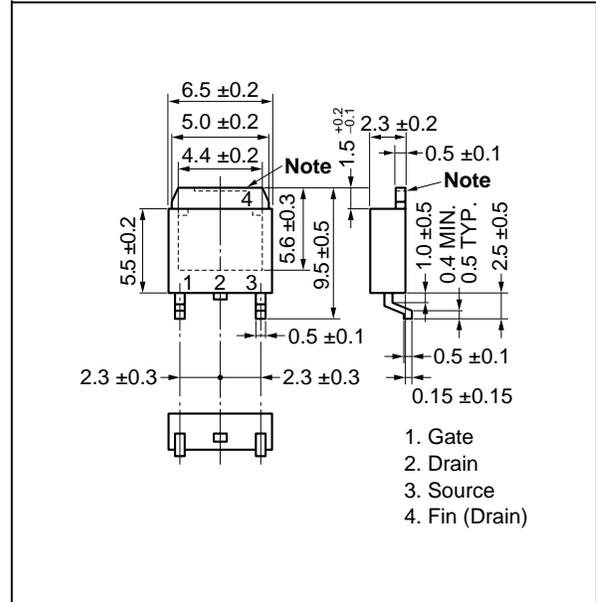


PACKAGE DRAWINGS (Unit: mm)

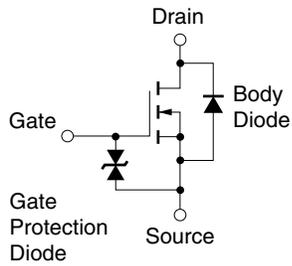
1) TO-251 (MP-3)



<R> 2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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